

# Buck Pulse Width Modulator Stepdown Voltage Regulator

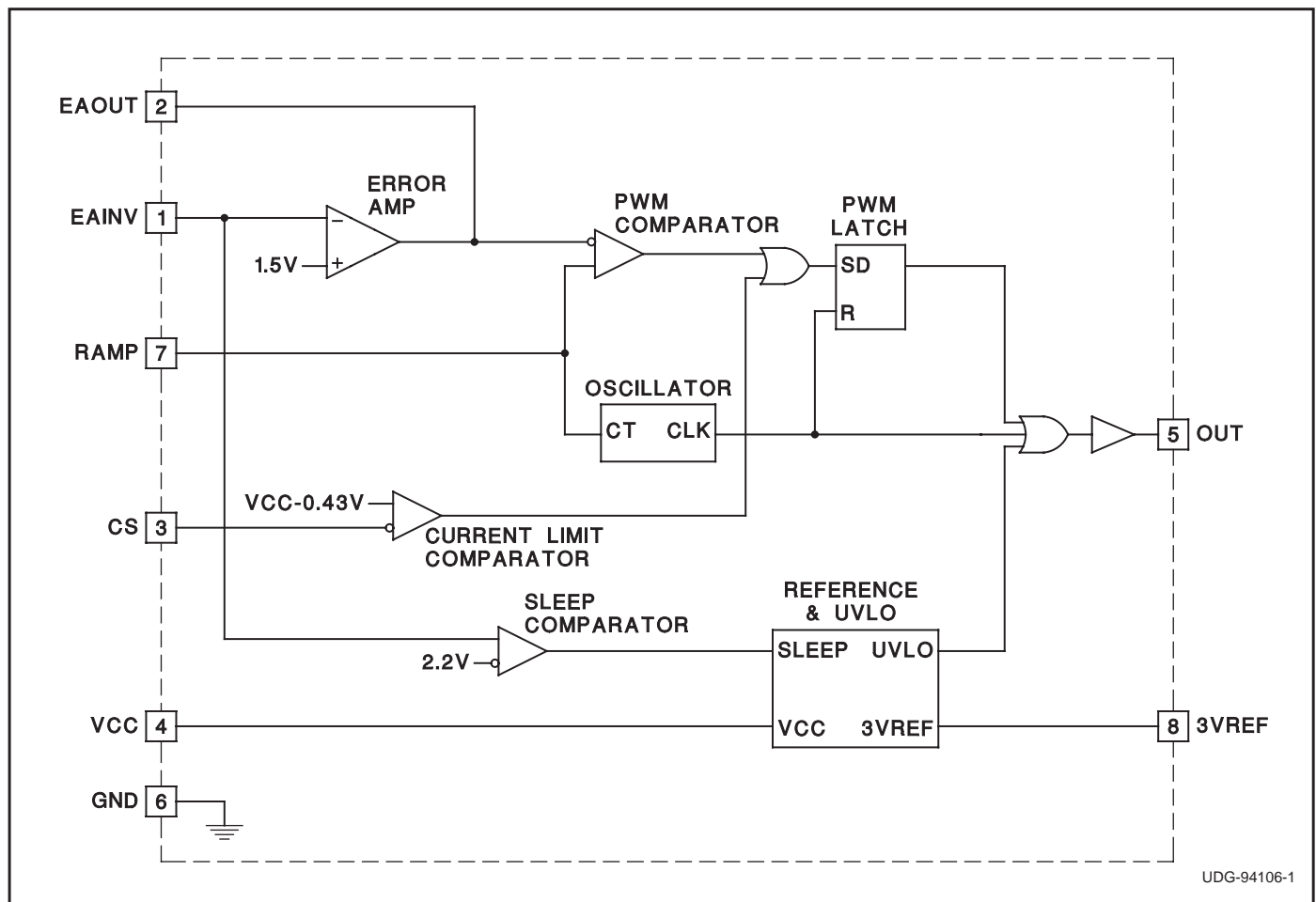
## FEATURES

- Simple Single Inductor Buck PWM Stepdown Voltage Regulation
- Drives External PMOS Switch
- Contains UVLO Circuit
- Includes Pulse-by-Pulse Current Limit
- Low 50 $\mu$ A Sleep Mode Current

## DESCRIPTION

The UC3573 is a Buck pulse width modulator which steps down and regulates a positive input voltage. The chip is optimized for use in a single inductor buck switching converter employing an external PMOS switch. The block diagram consists of a precision reference, an error amplifier configured for voltage mode operation, an oscillator, a PWM comparator with latching logic, and a 0.5A peak gate driver. The UC3573 includes an undervoltage lockout circuit to insure sufficient input supply voltage is present before any switching activity can occur, and a pulse-by-pulse current limit. Input current can be sensed and limited to a user determined maximum value. In addition, a sleep comparator interfaces to the UVLO circuit which turns the chip off when the input voltage is below the UVLO threshold. This reduces the supply current to only 50 $\mu$ A, making the UC3573 ideal for battery powered applications.

## BLOCK DIAGRAM



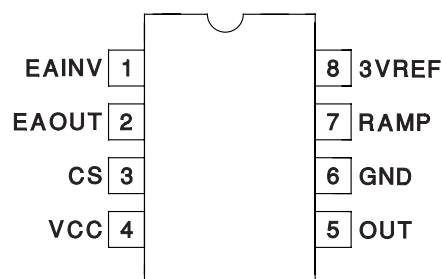
## ABSOLUTE MAXIMUM RATINGS

VCC	35V
EAINV	-0.6V to VCC
I <sub>EAOUT</sub>	25mA
RAMP	-0.3V to 4V
CS	-0.3V to VCC
I <sub>OUT</sub>	-0.7A to 0.7A
I <sub>3VREF</sub>	-15mA
Storage Temperature	-65°C to +150°C
Junction Temperature	-65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	+300°C

Currents are positive into, negative out of the specified terminal. Consult Packaging Section of Databook for thermal limitations and considerations of packages.

## CONNECTION DIAGRAMS

DIL-8, SOIC-8 (TOP VIEW)  
J or N, D Packages



**ELECTRICAL CHARACTERISTICS:** Unless otherwise specified, these parameters apply for  $T_A = -55^\circ\text{C}$  to  $+125^\circ\text{C}$  for the UC1573,  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  for the UC2573, and  $0^\circ\text{C}$  to  $+70^\circ\text{C}$  for the UC3573,  $V_{CC} = 5\text{V}$ ,  $C_T = 680\text{pF}$ ,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Reference Section</b>					
3VREF		2.94	3	3.06	V
Line Regulation	$V_{CC} = 4.75$ to $30\text{V}$		1	10	mV
Load Regulation	$I_{3VREF} = 0$ to $-5\text{mA}$		1	10	mV
<b>Oscillator Section</b>					
Frequency	$V_{CC} = 5\text{V}$ , $30\text{V}$	85	100	115	kHz
<b>Error Amp Section</b>					
EAINV	EAOUT = $2\text{V}$	1.45	1.5	1.55	V
I <sub>EAINV</sub>	EAOUT = $2\text{V}$		-0.2	-1	$\mu\text{A}$
AVOL	EAOUT = $0.5\text{V}$ to $3\text{V}$	65	90		dB
EAOUT High	EAINV = $1.4\text{V}$	3.6	4	4.4	V
EAOUT Low	EAINV = $1.6\text{V}$		0.1	0.2	V
I <sub>EAOUT</sub>	EAINV = $1.4\text{V}$ , EAOUT = $2\text{V}$	-350	-500		$\mu\text{A}$
	EAINV = $1.6\text{V}$ , EAOUT = $2\text{V}$	7	20		mA
Unity Gain Bandwidth	$T_J = 25^\circ\text{C}$ , $F = 10\text{kHz}$	0.6	1		MHz
<b>Current Sense Comparator Section</b>					
Threshold (referred to VCC)		-0.39	-0.43	-0.47	V
Input Bias Current	CS = VCC		150	800	nA
CS Propagation Delay			400		ns
<b>Gate Drive Output Section</b>					
OUT High Saturation	I <sub>OUT</sub> = 0		0	0.3	V
	I <sub>OUT</sub> = $-10\text{mA}$		0.7	1.5	V
	I <sub>OUT</sub> = $-100\text{mA}$		1.5	2.5	V
OUT Low Saturation	I <sub>OUT</sub> = $10\text{mA}$		0.1	0.4	V
	I <sub>OUT</sub> = $100\text{mA}$		1.5	2.2	V
Rise Time	$T_J = 25^\circ\text{C}$ , $C_{LOAD} = 1\text{nF} + 3.3\text{ Ohms}$		30	80	ns
Fall Time	$T_J = 25^\circ\text{C}$ , $C_{LOAD} = 1\text{nF} + 3.3\text{ Ohms}$		30	80	ns
<b>Pulse Width Modulator Section</b>					
Maximum Duty Cycle	EAINV = $1.4\text{V}$		92	96	%
Minimum Duty Cycle	EAINV = $1.6\text{V}$			0	%
Modulator Gain	EAOUT = $1.5\text{V}$ to $2.5\text{V}$	25	35	45	%/V
<b>Undervoltage Lockout Section</b>					
Start Threshold		3.5	4.2	4.5	V
Hysteresis		100	200	300	mV

**ELECTRICAL CHARACTERISTICS:** Unless otherwise specified, these parameters apply for  $T_A = -55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  for the UC1573,  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  for the UC2573, and  $0^{\circ}\text{C}$  to  $+70^{\circ}\text{C}$  for the UC3573,  $V_{CC} = 5\text{V}$ ,  $C_T = 680\text{pF}$ ,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Sleep Mode Section</b>					
Threshold		1.8	2.2	2.6	V
<b>Supply Current Section</b>					
$I_{VCC}$	$V_{CC} = 30\text{V}$		9	12	mA
$I_{VCC}$	$V_{CC} = 30\text{V}$ , $E_{AINV} = 3\text{V}$		50	150	$\mu\text{A}$

## PIN DESCRIPTIONS

**3VREF:** Precision 3V reference. Bypass with 100nF capacitor.

**CS:** Peak current limit sense pin. Senses the current across a current sense resistor placed between  $V_{CC}$  and source of the PMOS Buck switch. OUT will be held high (PMOS buck switch off) if  $V_{CC} - CS$  exceeds 0.4V.

**EAINV:** Inverting input to error amplifier.  $V_{OUT}$  sense feedback connected to this pin. The non-inverting input of the error amplifier is internally connected to:

$$\frac{3V_{REF}}{2} \text{ Volts.}$$

Connecting the EAINV pin to an external voltage greater than 2.6V commands the chip to go into a low current sleep mode.

**EAOUT:** Output of error amplifier. Use EAOUT and EAINV for loop compensation components.

**GND:** Circuit Ground.

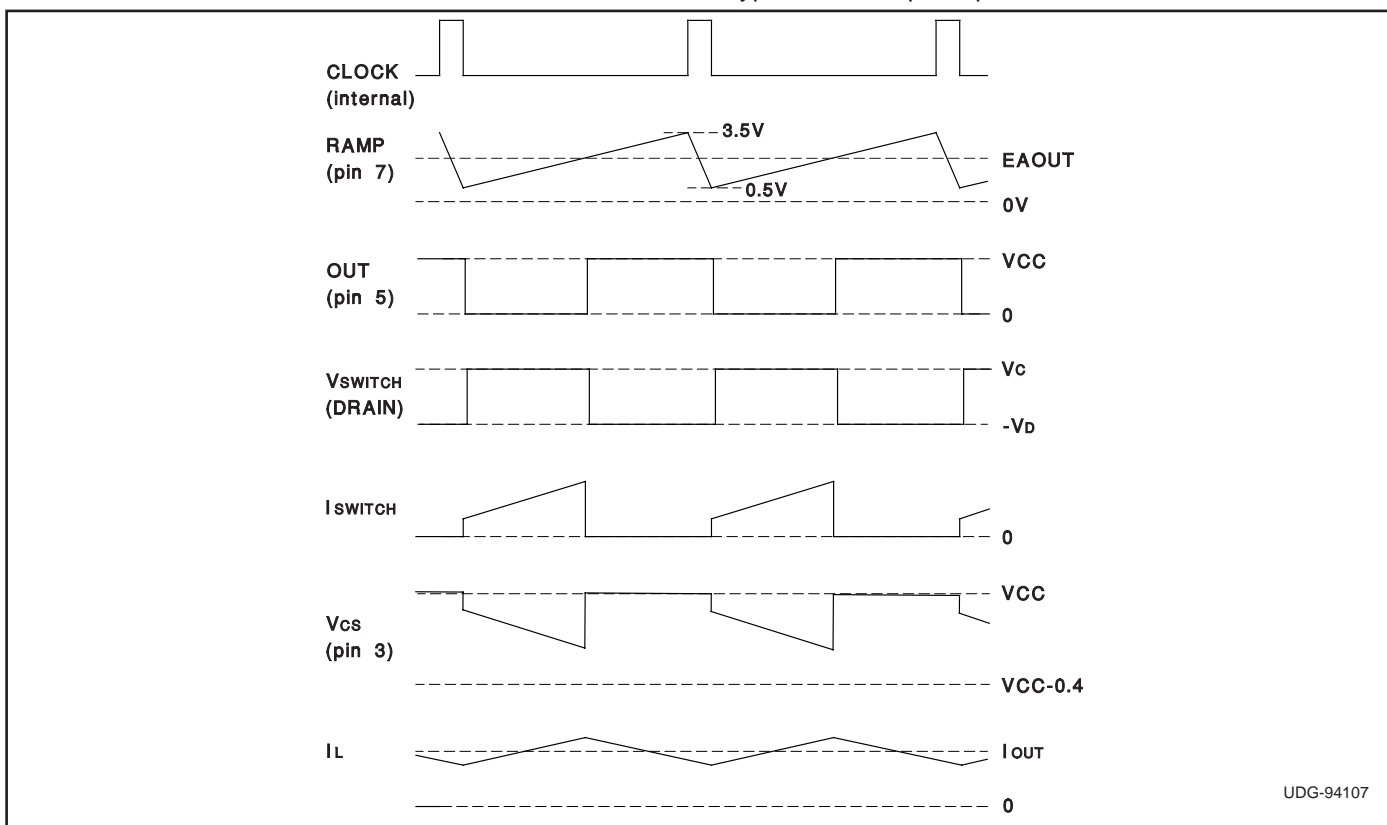
**OUT:** Gate drive for external PMOS switch connected between  $V_{CC}$  and the flyback inductor. OUT drives the gate of the PMOS switch between  $V_{CC}$  and GND.

**RAMP:** Oscillator and ramp for pulse width modulator. Frequency is set by a capacitor to GND by the equation

$$F = \frac{1}{15k \cdot C_{RAMP}}$$

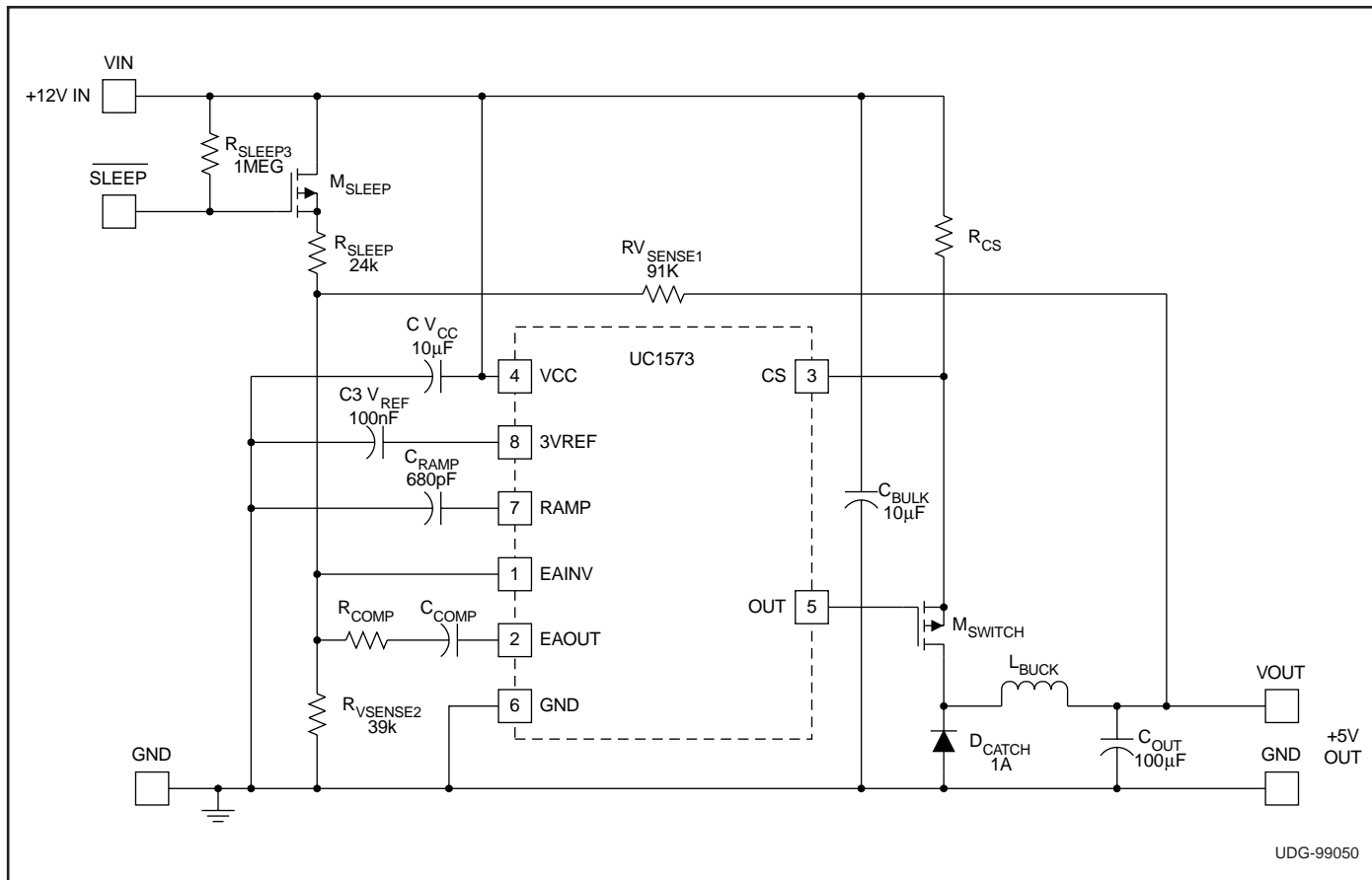
Recommended operating frequency range is 10kHz to 200kHz.

**VCC:** Input voltage supply to chip. Range is 4.75V to 30V. Bypass with a 1 $\mu\text{F}$  capacitor.



**Typical Waveforms.**

TYPICAL APPLICATION: 12V TO 5V BUCK CONVERTER



## **IMPORTANT NOTICE**

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

**CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.**

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.